# **DISCRETE SEMICONDUCTORS**

# DATA SHEET



BA482; BA483; BA484 Band-switching diodes

Product specification Supersedes data of January 1982 1996 Apr 17





## **Band-switching diodes**

BA482; BA483; BA484

#### **FEATURES**

## Continuous reverse voltage: max. 35 V

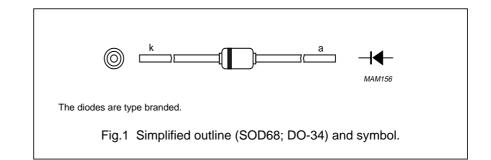
- Continuous forward current: max. 100 mA
- Low diode capacitance: max. 1.0 to 1.6 pF
- Low diode forward resistance: max. 0.7 to 1.2 Ω.

### **APPLICATION**

• VHF television tuners.

#### **DESCRIPTION**

Planar high performance band-switching diode in a hermetically sealed glass SOD68 (DO-34) package.



### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER		MAX.	UNIT
V <sub>R</sub>	continuous reverse voltage	_	35	V
I <sub>F</sub>	continuous forward current	_	100	mA
T <sub>stg</sub>	storage temperature	-65	+150	°C
Tj	junction temperature	_	150	°C

## **ELECTRICAL CHARACTERISTICS**

 $T_i = 25$  °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 100 mA; see Fig.2	_	1.2	V
I <sub>R</sub>	reverse current	see Fig.3			
		V <sub>R</sub> = 20V	_	100	nA
		V <sub>R</sub> = 20 V; T <sub>amb</sub> = 75 °C	_	1	μΑ
C <sub>d</sub>	diode capacitance	f = 1 to 100 MHz; V <sub>R</sub> = 3 V; see Fig.4			
	BA482		0.8	1.2	pF
	BA483		0.7	1.0	pF
	BA484		1.0	1.6	pF
r <sub>D</sub>	diode forward resistance	I <sub>F</sub> = 3 mA; f = 200 MHz; see Fig.5			
	BA482		0.6	0.7	Ω
	BA483		0.8	1.2	Ω
	BA484		0.8	1.2	Ω

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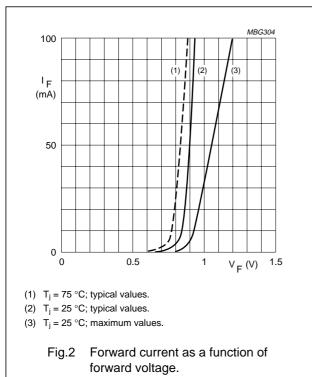
### THERMAL CHARACTERISTICS

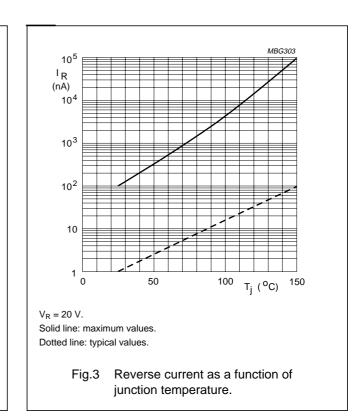
SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-tp</sub>	thermal resistance from junction to tie-point	lead length 10 mm	300	K/W
R <sub>th j-a</sub>	thermal resistance from junction to ambient	lead length 10 mm; note 1	500	K/W

#### Note

1. Device mounted on a FR4 printed-circuit board without metallization pad.

### **GRAPHICAL DATA**



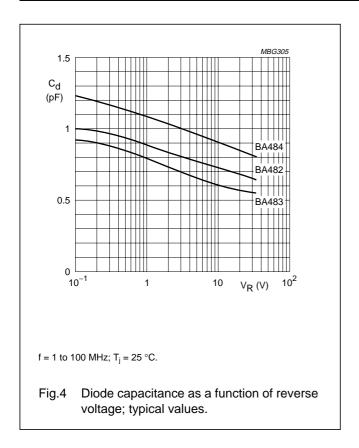


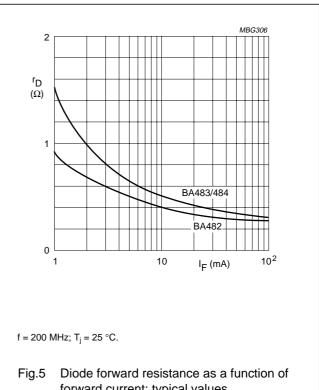
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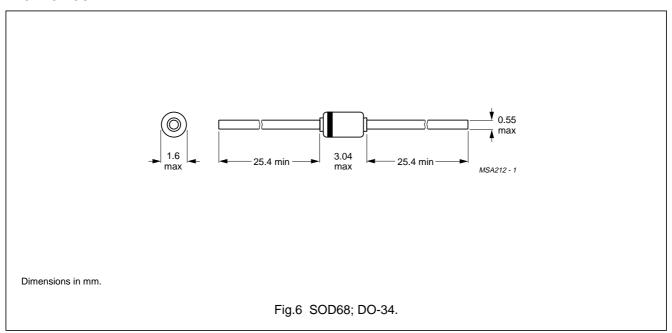


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#### **PACKAGE OUTLINE**



#### **DEFINITIONS**

Data Sheet Status		
Objective specification	This data sheet contains target or goal specifications for product development.	
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.	
Product specification	This data sheet contains final product specifications.	
Limiting values		

Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

## **Application information**

Where application information is given, it is advisory and does not form part of the specification.

## LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

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